## LED—OPR5200, OPR5200H

## T <br> Electronics

## Phototransistor—OPR5500

## Features:

- Stackable on 2 mm centers
- Vertical or horizontal mounting
- Automatic pick-and-place compatible
- Combine OPR5200 and OPR5500 to create miniature switch



## Description:

The OPR5200 is a miniature high efficiency GaAIAs light emitting diode in a high temperature polyamide chip carrier that is well suited to space-limited applications which require close channel spacing.

The OPR5500 is a miniature NPN silicon phototransistor housed in a high temperature polyamide chip carrier that is well suited to space-limited applications which require close channel spacing.

When combing the OPR5200 and OPR5500 (miniature phototransistor), this lateral mounting option can be used to create a non-focused reflective or slotted switch configuration.

These parts can be automatically placed with standard SMD equipment and can be reflow soldered by virtually any conventional means. Wraparound contacts allow it to be mounted face up or on edge for a beam direction parallel to the seating plane.

See Application Bulletin 237 for handling instructions

Applications:

- Slotted switches
- Industrial environments
- Space-limited applications

| Ordering Information |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Part Number | LED Peak Wavelength | Output Power ( $\mu \mathrm{W}$ ) Min | $\begin{gathered} \mathrm{I}_{\mathrm{F}}(\mathrm{~mA}) \\ \mathrm{Typ} / \mathrm{Max} \end{gathered}$ | Total Beam Angle (Degrees) | Rise / Fall Times (nS) Typ | Packaging |
| OPR5200 | 890 nm | 350 | 20 / 50 | 90 | $500 / 250$ | Chip Tray |
| OPR5200H | 880 nm | 500 | 20/50 | 90 | 20/20 | Chip Tray |
| Part <br> Number | Sensor | Light Current $I_{\text {C(ON) }}(\mu A)$ Min | $\mathrm{V}_{\mathrm{CE}}$ <br> Max | Input Power $\mathrm{E}_{\mathrm{E}}$ $\left(\mu \mathrm{W} / \mathrm{cm}^{2}\right)$ | Viewing Angle (Degrees) | Packaging |
| OPR5500 | Transistor | 36 | 30 | 150 | 120 | Chip Tray |



TOLERANCE IS $\pm .005$ [0.13]


RoHS


DIMENSIONS ARE IN:


| OPR5500 |  |
| :---: | :---: |
| Pin \# | Transistor |
| 1 | Collector |
| 2 | Emitter |
| 3 | Base |

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## Miniature Surface Mount

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## Phototransistor—OPR5500

## Electrical Specifications

OPR5200 Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Storage and Operating Temperature | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| :--- | ---: |
| Continuous Forward Current | 50 mA |
| Peak Forward Current (1 $\mu$ s pulse width, $10 \%$ duty cycle) OPR5200 | 1.0 A |
| Peak Forward Current (1 $\mu$ s pulse width, $10 \%$ duty cycle) OPR5200H | 400 mA |
| Power Dissipation $^{(1)}$ | 100 mW |
| Solder reflow time within $5^{\circ} \mathrm{C}$ of peak temperature is 20 to 40 seconds ${ }^{(2)}$ | $250^{\circ} \mathrm{C}$ |

OPR5200 Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{P}_{0}$ | Output Power | 350 | - | - | $\mu \mathrm{W}$ | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| $\mathrm{V}_{\mathrm{F}}$ | Forward Voltage | - | - | 1.8 | V | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| $I_{R}$ | Reverse Current | - | - | 100 | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{R}}=2 \mathrm{~V}$ |
| $\lambda_{P}$ | Peak Wavelength | - | 890 | - | nm | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| $\lambda_{\text {BW }}$ | Spectral Bandwidth | - | 80 | - | nm | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| $\theta_{\text {HP }}$ | Emission Angle | - | $\pm 45^{\circ}$ | - | - | at half power points |
| $\mathrm{t}_{\mathrm{r}}$ | Output Rise Time | - | 500 | - | ns | $\mathrm{I}_{\mathrm{P}}=100 \mathrm{~mA}, \mathrm{PW}=10.0 \mu \mathrm{~s}, \mathrm{D} . \mathrm{C} .=10 \%$ |
| $\mathrm{t}_{\mathrm{f}}$ | Output Fall Time | - | 250 | - | ns |  |

Notes:
(1) Derate at $1.00 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$.
(2) Solder time less than 5 seconds at temperature extreme.

OPR5200H Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Po | Output Power OPR5200H | 500 | - | - | $\mu \mathrm{W}$ | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| $\mathrm{V}_{\mathrm{F}}$ | Forward Voltage | - | 1.40 | 1.80 | V | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Current | - | - | 10 | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{R}}=5 \mathrm{~V}$ |
| $\lambda_{P}$ | Peak Wavelength | - | 883 | - | nm | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| $\lambda_{\text {BW }}$ | Spectral Bandwidth | - | 55 | - | nm | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| $\theta_{\text {HP }}$ | Emission Angle | - | $\pm 45^{\circ}$ | - | - | at half power points |
| $\mathrm{t}_{\mathrm{r}}$ | Output Rise Time | - | 20 | - | ns |  |
| $\mathrm{t}_{\mathrm{f}}$ | Output Fall Time | - | 20 | - | ns | ( |

Notes:
(1) Derate at $1.00 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$.
(2) Solder time less than 5 seconds at temperature extreme.

Phototransistor-OPR5500

## Electrical Specifications

OPR5500 Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Storage and Operating Temperature | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| :--- | ---: |
| Collector-Emitter Voltage | 30 V |
| Emitter-Collector Voltage | 5 V |
| Power Dissipation ${ }^{(1)}$ | 100 mW |
| Solder reflow time within $5^{\circ} \mathrm{C}$ of peak temperature is 20 to 40 seconds ${ }^{(2)}$ | $250^{\circ} \mathrm{C}$ |

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| :---: | :--- | :---: | :---: | :---: | :---: | :--- |
| $\mathrm{I}_{\mathrm{C}(\mathrm{ON})}$ | On-State Collector Current | 36 | - | - | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{E}_{\mathrm{e}}=150 \mu \mathrm{~W} / \mathrm{cm}^{2}$ <br> $(890 \mathrm{~nm}$ light source) |
| $\mathrm{I}_{\text {CEO }}$ | Dark Current | - | - | 100 | nA | $\mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{E}_{\mathrm{e}}=0$ |
| $\mathrm{~V}_{\text {(BR)CEO }}$ | Collector-Emitter Breakdown Voltage | 30 | - | - | V | $\mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A}$ |
| $\mathrm{~V}_{\text {(BR)ECO }}$ | Emitter-Collector Breakdown Voltage | 5 | - | - | V | $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}$ |
| $\mathrm{~V}_{(\text {SAT })}$ | Saturation Voltage | - | - | 0.4 | V | $\mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A}, \mathrm{E}_{\mathrm{e}}=5 \mathrm{~mW} / \mathrm{cm}^{2}$ |
| $\mathrm{t}_{\mathrm{r}, \mathrm{t}_{\mathrm{f}}}$ | Output Rise and Fall Time | - | 2.5 | - | $\mu \mathrm{s}$ | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=800 \mu \mathrm{~A}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ |

Notes:
(1) Derate at $1.00 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$.
(2) Solder time less than 5 seconds at temperature extreme.

# Performance 

OPR5200



## OPR5500



